Unit: mm

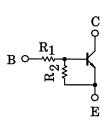
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1114, RN1115, RN1116, RN1117, RN1118

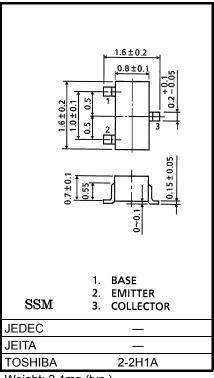
Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- With built-in bias resistors.
- Simplified circuit design
- Reduced number of parts and simplified manufacturing process
- Complementary to RN2114 to 2118

Equivalent Circuit and Bias Resistor Values



Type No.	R ₁ (kΩ)	R ₂ (kΩ)
RN1114	1	10
RN1115	2.2	10
RN1116	4.7	10
RN1117	10	4.7
RN1118	47	10



Weight: 2.4mg (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristi	Symbol	Rating	Unit		
Collector-base voltage	RN1114 to 1118	V_{CBO}	50	V	
Collector-emitter voltage	KN1114 to 1116	V _{CEO}	50	V	
Emitter-base voltage	RN1114		5	V	
	RN1115		6		
	RN1116	V_{EBO}	7		
	RN1117		15		
	RN1118		25		
Collector current		Ic	100	mA	
Collector power dissipation	RN1114 to 1118	PC	100	mW	
Junction temperature	KINTTI4 (0 1110	Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

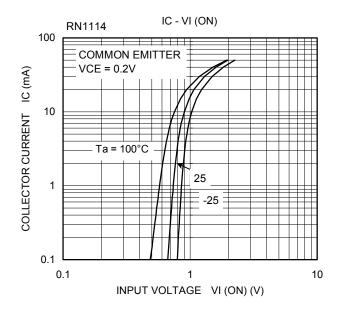
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

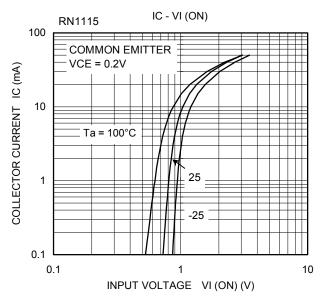
Start of commercial production 1994-08

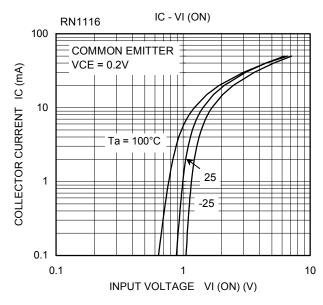


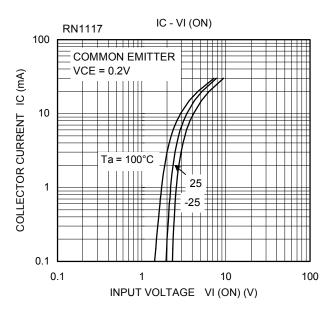
Electrical Characteristics (Ta = 25°C)

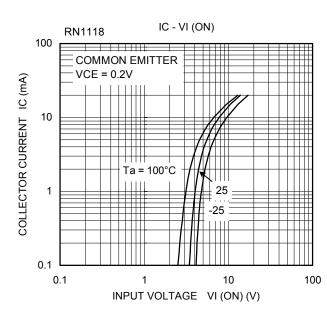
Characte	ristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1114 to 1118	I _{CBO}	_	V _{CB} = 50 V, I _E = 0	_	_	100	nA
	RN1114 to 1118	I _{CEO}	_	V _{CE} = 50 V, I _B = 0	_	_	500	nA
	RN1114	I _{EBO}	_	V _{EB} = 5 V, I _C = 0	0.35	_	0.65	mA
	RN1115		_	V _{EB} = 6 V, I _C = 0	0.37	_	0.71	
Emitter cut-off current	RN1116		_	V _{EB} = 7 V, I _C = 0	0.36	_	0.68	
	RN1117		_	V _{EB} = 15 V, I _C = 0	0.78	_	1.46	
	RN1118		_	V _{EB} = 25 V, I _C = 0	0.33	_	0.63	
DC summent assis	RN1114 to 16, 18	h _{FE}	_	V _{CE} = 5 V, I _C = 10 mA	50	_	-	_
DC current gain	RN1117		_		30	_	_	
Collector-emitter saturation voltage	RN1114 to 1118	V _{CE} (sat)	_	I _C = 5 mA, I _B = 0.25 mA	_	0.1	0.3	٧
	RN1114		_		0.6	_	2.0	V
	RN1115		_		0.7	_	2.5	
Input voltage (ON)	RN1116	VI (ON)	_	V _{CE} = 0.2 V, I _C = 5 mA	0.8	_	2.5	
	RN1117		_		1.5	_	3.5	
	RN1118		_		2.5	_	10.0	
	RN1114	V _I (OFF)	_	V _{CE} = 5 V, I _C = 0.1 mA	0.3	_	0.9	V
	RN1115		_		0.3	_	1.0	
Input voltage (OFF)	RN1116		_		0.3	_	1.1	
	RN1117		_		0.3	_	2.3	
	RN1118		_		0.5	_	5.7	
Transition frequency	RN1114 to 1118	f _T	_	V _{CE} = 10 V, I _C = 5 mA	_	250	1	MHz
Collector output capacitance	RN1114 to 1118	C _{ob}	_	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	3.0	6.0	pF
	RN1114	R ₁	_	_	0.7	1.0	1.3	kΩ
Input Resistor	RN1115		_		1.54	2.2	2.86	
	RN1116		_		3.29	4.7	6.11	
	RN1117		_		7.0	10.0	13.0	
	RN1118		_		32.9	47.0	61.1	
Resistor Ratio	RN1114	R ₁ /R ₂	_	_	_	0.1	_	_
	RN1115		_		_	0.22	_	
	RN1116		_		_	0.47	_	
	RN1117		_		_	2.13	_	
	RN1118		_		_	4.7	_	

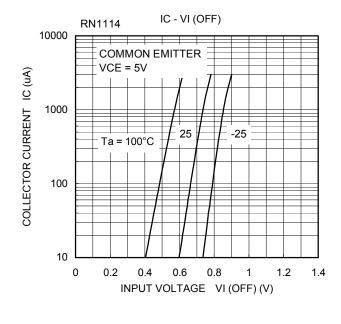


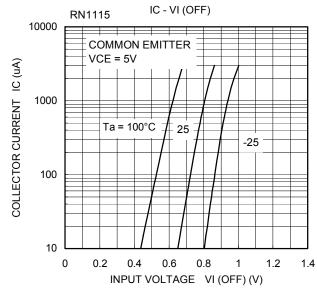


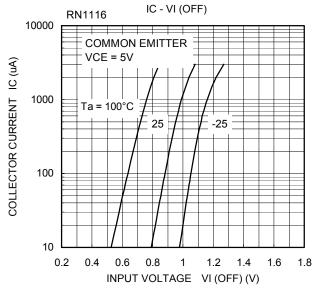


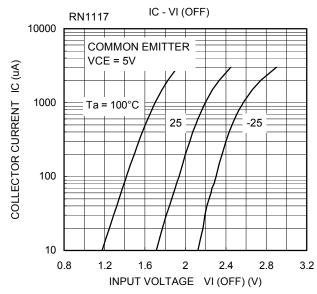


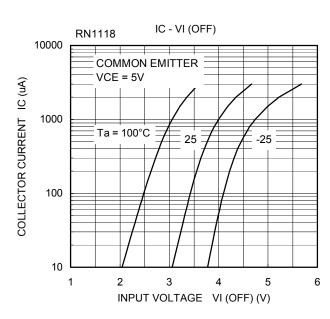


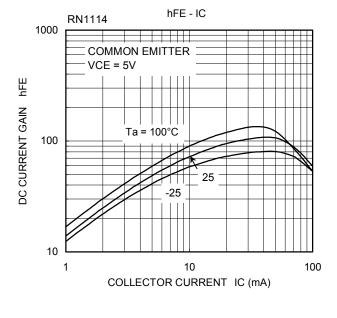


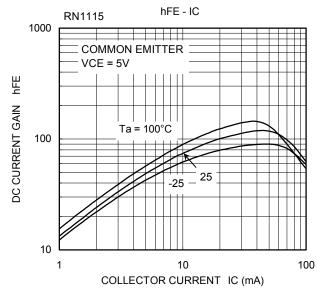


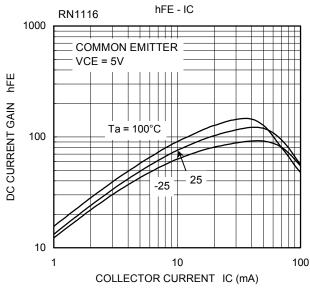


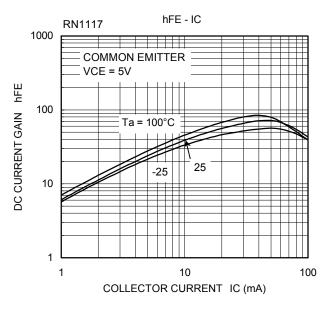


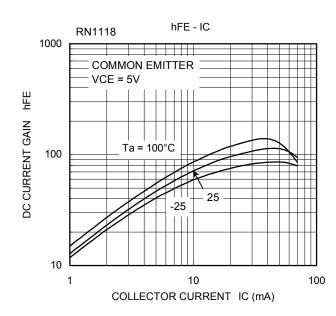


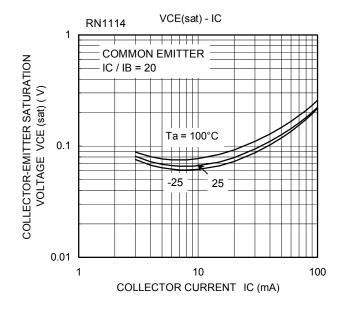


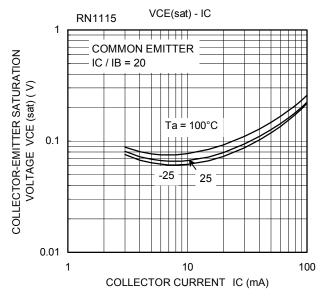


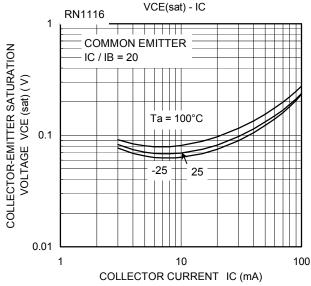


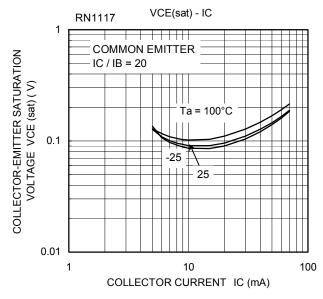


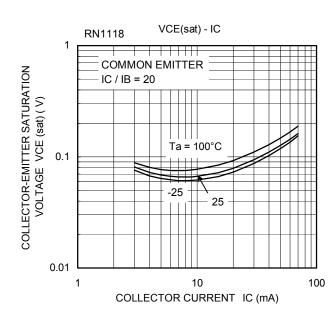












Type Name	Marking
RN1114	Type Name X Q
RN1115	Type Name X S
RN1116	Type Name XT
RN1117	Type Name
RN1118	Type Name X W

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